

N-Channel MOSFET

Features

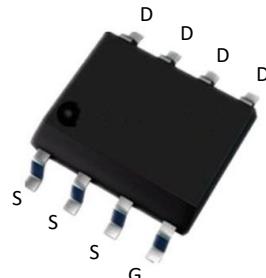
- Advanced high cell density Trench technology
- Super Low Gate Charge
- Excellent CdV/dt effect decline
- Green Device Available

Product Summary

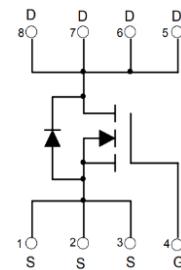
| V_{DS} | $R_{DS(ON)} \text{ MAX}$ | $I_D \text{ MAX}$ |
|----------|--------------------------|-------------------|
| 30V | 16mΩ@10V | 10A |
| | 23mΩ@4.5V | |

Application

- High Frequency Point-of-Load Synchronous Buck Converter for MB/NB/UMPC/VGA
- Networking DC-DC Power System
- Load Switch



SOP-8 top view



Schematic diagram

Absolute Maximum Ratings (TA=25°C unless otherwise noted)

| Symbol | Parameter | Rating | Unit |
|--------|-----------|--------|------|
|--------|-----------|--------|------|

Common Ratings (TC=25°C Unless Otherwise Noted)

| | | | |
|-----------|----------------------------------|------------|----|
| V_{DS} | Drain-Source Breakdown Voltage | 30 | V |
| V_{GS} | Gate-Source Voltage | ±20 | V |
| T_J | Maximum Junction Temperature | 150 | °C |
| T_{STG} | Storage Temperature Range | -55 to 150 | °C |
| I_S | Diode Continuous Forward Current | 10 | A |

Mounted on Large Heat Sink

| | | | | |
|-----------|---|---------|-----|------|
| I_{DM} | Pulse Drain Current Tested | Tc=25°C | 40 | A |
| I_D | Continuous Drain Current@GS=10V | Tc=25°C | 10 | A |
| P_D | Maximum Power Dissipation | Tc=25°C | 1.4 | W |
| $R_{θJA}$ | Thermal Resistance Junction-Ambient(*1 in2 Pad of 2-oz Copper), Max.) | | 89 | °C/W |

| Electrical Characteristics (T_J=25°C unless otherwise noted) | | | | | | |
|--|----------------------------------|--|------------|------------|------------|-------------|
| Symbol | Parameter | Condition | Min | Typ | Max | Unit |
| Static Electrical Characteristics @ T_J = 25°C (unless otherwise stated) | | | | | | |
| BV _{(BR)DSS} | Drain-Source Breakdown Voltage | V _{GS} =0V, ID=250μA | 30 | -- | -- | V |
| I _{DSS} | Zero Gate Voltage Drain Current | V _{DS} =30V, V _{GS} =0V | -- | -- | 1 | μA |
| I _{GSS} | Gate-Body Leakage Current | V _{GS} =±20V, V _{DS} =0V | -- | -- | ±100 | nA |
| V _{GS(th)} | Gate Threshold Voltage | V _{DS} =V _{GS} , ID=250μA | 1 | 1.5 | 2.5 | V |
| R _{DS(on)} | Drain-Source On-State Resistance | V _{GS} =10V, ID=8A | -- | 11.5 | 16 | mΩ |
| | | V _{GS} =4.5V, ID=6A | -- | 18 | 23 | |
| Dynamic Electrical Characteristics @ T_J = 25°C (unless otherwise stated) | | | | | | |
| C _{ISS} | Input Capacitance | V _{DS} =15V, V _{GS} =0V, f=1MHz | -- | -- | 1250 | pF |
| C _{OSS} | Output Capacitance | | -- | 180 | -- | pF |
| C _{RSS} | Reverse Transfer Capacitance | | -- | 110 | -- | pF |
| Switching Characteristics | | | | | | |
| Q _g | Total Gate Charge | V _{DS} =15V, ID=8A, V _{GS} =10V | -- | 15 | -- | nC |
| Q _{gs} | Gate Source Charge | | -- | 2.5 | -- | nC |
| Q _{gd} | Gate Drain Charge | | -- | 3 | -- | nC |
| t _{d(on)} | Turn-on Delay Time | V _{DS} =15V, RL=1.8Ω, V _{GS} =10V, RG=3Ω | -- | 5 | -- | nS |
| t _r | Turn-on Rise Time | | -- | 3.5 | -- | nS |
| t _{d(off)} | Turn-Off Delay Time | | -- | 19 | -- | nS |
| t _f | Turn-Off Fall Time | | -- | 3.5 | -- | nS |
| Source- Drain Diode Characteristics | | | | | | |
| V _{SD} | Forward on voltage | T _J =25°C, I _s =1A, | -- | -- | 1.2 | V |

Typical Operating Characteristics

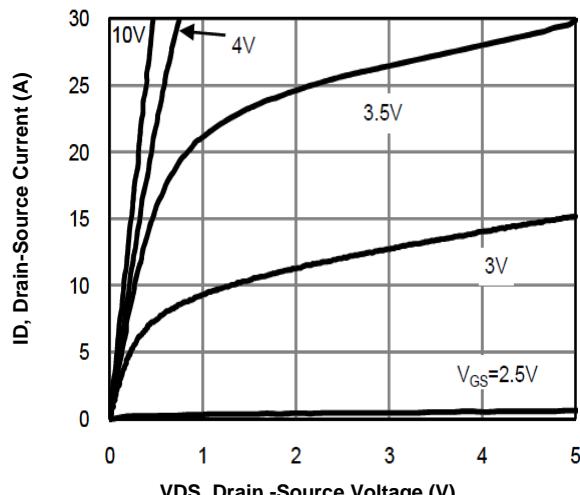


Fig1. Typical Output Characteristics

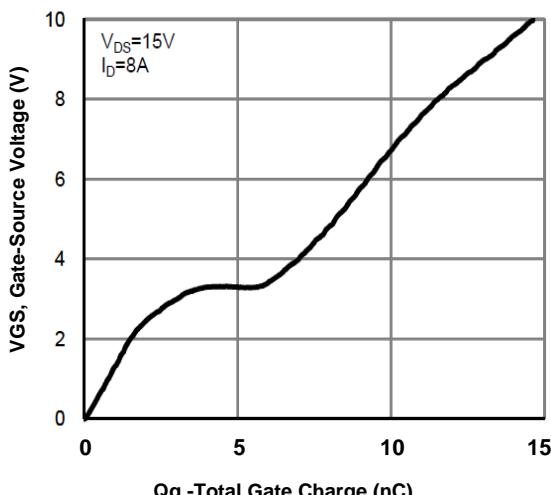


Fig2. Typical Gate Charge Vs.Gate-Source Voltage

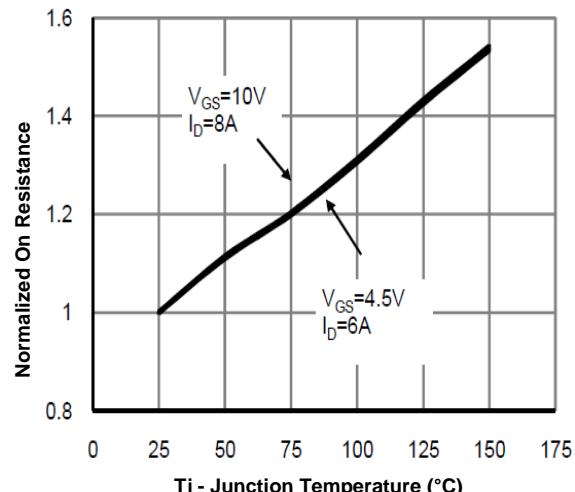


Fig3. Normalized On-Resistance Vs. Temperature

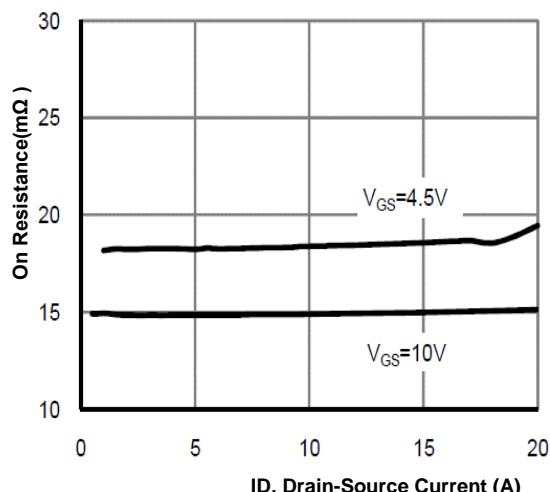


Fig4. On-Resistance Vs. Drain-Source Current

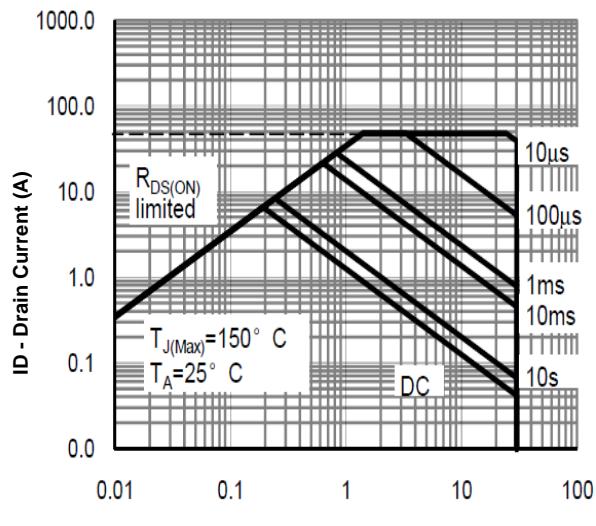


Fig5. Maximum Safe Operating Area

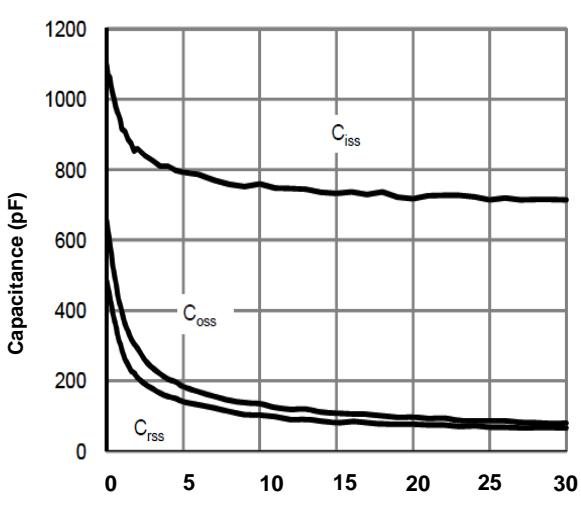
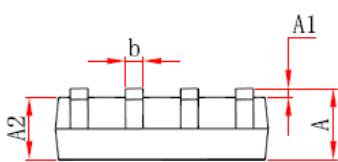
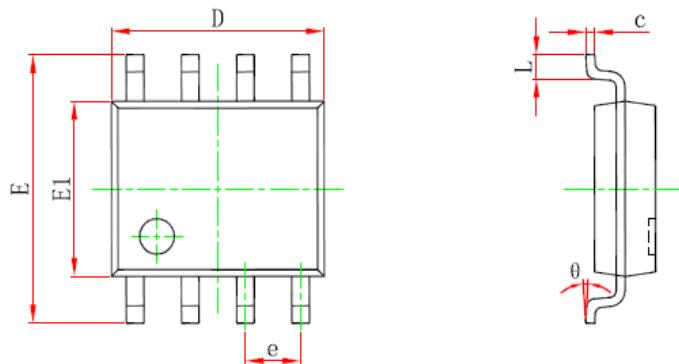


Fig6 Typical Capacitance Vs.Drain-Source Voltage

SOP-8 Package information



| Symbol | Dimensions In Millimeters | | Dimensions In Inches | |
|--------|---------------------------|-------|----------------------|-------|
| | Min | Max | Min | Max |
| A | 1.450 | 1.750 | 0.053 | 0.069 |
| A1 | 0.100 | 0.250 | 0.004 | 0.010 |
| A2 | 1.350 | 1.550 | 0.053 | 0.061 |
| b | 0.330 | 0.510 | 0.013 | 0.020 |
| c | 0.170 | 0.250 | 0.007 | 0.010 |
| D | 4.700 | 5.100 | 0.185 | 0.201 |
| e | 1.270 (BSC) | | 0.050 (BSC) | |
| E | 5.800 | 6.200 | 0.228 | 0.244 |
| E1 | 3.800 | 4.000 | 0.150 | 0.157 |
| L | 0.400 | 1.270 | 0.016 | 0.050 |
| θ | 0° | 8° | 0° | 8° |